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Quantitative analysis and near-field observation of strong coupling between plasmonic nanogap and silicon waveguides

Rafael Salas-Montiel,1,a) Aniello Apuzzo,1 Cécile Delacour,2,b) Zohreh Sedaghat,1 Aurélien Bruyant,1 Philippe Grosse,2 Alexei Chelnokov,2 Gilles Lerondel,3 and Sylvain Blaize1,c)

1LNIO, CNRS UMR 6279, UTT, 12 rue Marie Curie, 10010 Troyes, France
2CEA Leti Minatec Campus, DOPT, 17 rue des Martyrs, 38054 Grenoble, France
(a)Electronic mail: rafael.salas@utt.fr.
(b)Present address: Institut Néel, 25 av. des Martyrs, 38042 Grenoble.
(c)Electronic mail: sylvain.blaize@utt.fr.

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We present a near field optical study of a plasmonic gap waveguide vertically integrated on silicon. The experimental study is based on a near field scanning optical microscope configured in perturbation mode. This operation mode is described and modeled to give a physical insight into the measured signal. A high spatial resolution allows for the characteristics of the plasmonic gap modes, such as near field distributions, effective indices, direction of propagation, and coupling between perpendicularly polarized modes, to be imaged and analyzed with accuracy. This experimental work is supported by numerical simulations based on finite element optical mode solvers and by the application of the strongly coupled-mode theory to the device. © 2012 American Institute of Physics. [http://dx.doi.org/10.1063/1.4725511]

Plasmonic structures, such as plasmonic gap waveguides, allow for guiding surface plasmon modes with high confinement and relatively low propagation losses at optical frequencies. The confinement enables a strong enhancement of the electric field inside the nanogap that can be exploited in surface-enhanced spectroscopy,1 biosensing,2 and plasmonic nanocircuitry.3,4 In addition, plasmonic gap waveguides can be further functionalized with active materials such as quantum dots for single quantum emitter applications or loss compensation.5 Efficient excitation of gap modes has been demonstrated experimentally with the use of nanoantennas6,7 and tapered silicon waveguides8 with efficiencies as high as 20% and 35%. More recently, directional coupling between plasmonic gap and silicon waveguides was demonstrated with a coupling efficiency of 60%.9 Today, with the development of techniques such as electron energy-loss spectroscopy10 and near field scanning optical microscopy (NSOM), it is possible to study surface plasmon waves such as plasmon gap modes directly.11,12 For waveguiding structures, collection-mode NSOM (Ref. 13) or photon scanning tunneling microscopy14 have been used for the direct mapping of local field distributions of surface plasmons. In this work, we use a more convenient NSOM for the measurement of integrated plasmonic structures. It consists of a conventional integrated optics setup and a commercial AFM probe set to intermittent mode (Fig. 1). A full description of the setup can be found in Ref. 21.

The surface plasmon gap mode, supported by the copper waveguide (Fig. 2(a)), is efficiently coupled from the Si

In order to so, we studied a vertically integrated plasmonic gap waveguide on Si. This experimental work is supported by the theoretical analysis of the device through the finite element optical mode solvers and the strongly coupled mode theory.

The structure, fabricated with standard Si technology at CEA-Leti, is a vertical directional coupler with Si photonics and Cu gap waveguides. Details of the design and fabrication process can be found in Ref. 9. The setup used for the optical near field measurements is an arrangement of a conventional integrated optics setup and a commercial AFM probe set to intermittent mode (Fig. 1). A full description of the setup can be found in Ref. 21.

The surface plasmon gap mode, supported by the copper waveguide (Fig. 2(a)), is efficiently coupled from the Si

FIG. 1. (a) A 3D artwork of the vertically integrated plasmonic waveguide on Si. (b) SEM image of the AFM probe with a radius of 2 nm. (c) Setup for the measurement of the optical near field.
waveguide. This mode propagates through the plasmonic waveguide and is coupled back to output Si waveguide to reach the detector (Fig. 2(b)). The Si waveguide was excited by its fundamental quasi-TE mode at a wavelength of 1550 nm. From the optical image, we plotted a longitudinal profile along the gap waveguide.

Because the AFM probe scans the structure over its surface, only the plasmonic waveguide can be imaged. The optical image shows, however, the incident and transmitted optical modes supported by the Si waveguides. The propagation of the gap mode is clearly seen along the plasmonic waveguide, apparently, without propagation loss. The standing wave pattern, with a period $\Lambda = 460 \pm 60$ nm, can be observed (Fig. 2(c)) as a result of the interference between the co- and counter-propagating gap modes. Modal and propagation characteristics such as effective indices and mode profiles can be obtained by the use of this NSOM in perturbation mode for both waveguides. For the Cu gap waveguide, $\beta_2 = \pi/\Lambda = 6.83 \pm 0.22 \mu m^{-1}$, which is consistent with optical mode solvers calculations.

The efficient excitation of the gap mode is the result of strong coupling between the Si and Cu waveguides as illustrated in Fig. 3. The vertical coupler is excited through the fundamental mode of the single mode Si waveguide. This incident field can be decomposed into the two modes supported by the coupler and propagated through it. After a propagation length ($l$), the power is transferred to the Cu waveguide. However, not all the power is transferred to the Cu waveguide because of the overlapping between modes of the individual waveguides and because the waveguides have a completely different index profiles.

To investigate the efficiency of the coupler, we have calculated the power transfer efficiency ($\eta$) as a function of the separation distance ($e$) between the two waveguides. The calculations were done using a strongly coupled-mode theory valid for lossy systems. The efficiency is defined as the ratio of the optical power at the output of the Cu waveguide to the power at the input of the Si waveguide. The modified propagation constants ($\gamma_{a,b}$) and coupling coefficients ($K_{ab}$) include the overlap integrals between the fundamental modes of the individual waveguides ($C_{ab}, C_{ba}$). These four parameters are

$$\gamma_{a,b} = \beta_{1,2} + (k_{11,22} - C \cdot k_{21,12})/(1 - C^2),$$

$$K_{ab,ba} = (k_{12,21} - k_{22,11} \cdot C)/(1 - C^2),$$

where $\beta_1$ and $\beta_2$ are the propagation constants of the isolated waveguides and $k_{12}$ and $k_{21}$ are the conventional coupling coefficients. The parameter $C$ is defined as $C = (C_{ab} + C_{ba})/2$, where $C_{pq} = \frac{1}{4} \int_{-\infty}^{\infty} [\vec{E}_{p}^{(q)} \times \vec{H}_{q}^{(p)}]^2 \, dx \, dy$ is the overlap integral coefficient. This coefficient is a measure of the proximity of the waveguides. The four parameters in Eqs. (1) and (2) should include the overlap integral to obtain accurate efficiency results and to satisfy the power conservation law. For maximum power transfer, the coupling length $l$ is chosen such that $\psi I = \pi/2$, where $\psi = (\Delta^2 + K_{ab} \cdot K_{ba})^2$ and $\Delta = (\gamma_{a,b})/2$.

The electric and magnetic field distributions of the individual waveguides were calculated with a commercial finite element optical mode solver. The opto-geometrical parameters of the structure were taken from Ref. 9. The results are shown in Fig. 3, where the Si and Cu waveguides are labeled as a and b.

The real part of the propagation constant $\gamma_a$ decreases as the separation distance $e$ increases. In contrast, $\gamma_b$ remains almost constant as the separation distance $e$ increases. Therefore, the effects of modal interactions are higher for the propagation constant of the silicon waveguide than that for the copper waveguide for short separation distances $e$. As expected, the overlapping decreases as the separation distance increases, which leads to a weakly coupled regime.
However, the strong coupling regime is observed with as much as 200 nm of separation between the waveguides ($C_{ab}, C_{ab} \gg 0.1$). For short separation distances ($s \ll 45$ nm), the coupling coefficient $k_{ba}$ is higher than $k_{ab}$. From this calculation, we can infer that the Si waveguide is strongly perturbed by the presence plasmonic gap waveguide and therefore an efficient coupling can exist. A maximum efficiency is reached at a separation distance of 45 nm, for which $k_{ab} = k_{ba}$. From that separation distance, the efficiency starts to decrease. Looking at a separation distance of 45 nm and a coupling length $L_c = 0.8 \mu m$, a 60% coupling efficiency is calculated, which is consistent with the measurements already reported in Ref. 9. Finally, the optical power carried by each waveguide, $P_a$ and $P_b$, is plotted in Fig. 3(e). We observe the power transfer from one waveguide to the other as the propagation distance increase. This transfer decays exponentially as a result of the propagation loss of the plasmonic waveguide.

To interpret the NSOM images (Fig. 2(b)), we present a model of the quantity that is measured by the NSOM in perturbation mode. For that, we inspect each path segment along the structure to obtain the quantity that is measured by the detector (Fig. 1(c)). If we call $P_{in}$, the optical power injected in the waveguiding structure, the optical powers measured just before the probe and at the waveguide output are given by

$$P_1(z_0) = T_1(z_0) \cdot P_{in},$$  (3)
$$P_{out} = T_2(L_z - z_0) \cdot P_2,$$  (4)

respectively, where $T_1$ and $T_2$ are the power transmission coefficients between the input of the waveguide and the probe located at $z_0$ and between the probe and the output of the waveguide located at $z = L_z$. By combination of Eqs. (3) and (4), we obtain

$$\frac{P_2(z_0)}{P_1(z_0)} = \frac{P_{out}}{P_{in}} \cdot \frac{1}{T_2(L_z - z_0) \cdot T_1(z_0)}.$$  (5)

On the other hand, the optical power immediately after the probe can be written as

$$P_2(z_0) = P_1(z_0) - P_{sca}(z_0),$$  (6)

where $P_{sca}$ is the power scattered by the apex of the probe.

By considering that the longitudinal polarizability of the sharp probe apex ($y$ axis) is higher than the polarizability of its transversal components, the expression of $P_{sca}$ can be written as

$$P_{sca} = Q^y \frac{1}{2} \sqrt{\frac{\mu_0}{\epsilon_0}} |E_y|^2,$$  (7)

where $E_y$ is the $y$ component of the local electric field and $Q^y$ is the scattering cross section for the field parallel to the probe axis. The $Q^y$ value depends on the probe and sample material geometry and on the local density of radiation modes. The modeling of $Q^y$ is therefore a complex problem that in most cases requires tedious numerical calculations. Here, we would like to point out that the probe scatters the $y$-component of the electrical field more efficiently.

To explicitly state the quantity that is measured with this configuration, we can combine Eqs. (5) and (6) to obtain

$$\frac{P_{out}}{P_{in}} = T_2 T_1 \left[ 1 - \frac{P_{sca}(z_0)}{P_1(z_0)} \right].$$  (8)

From this last equation, it follows that the measured quantity is proportional to the intensity of the local electric field normalized to the guided power flux at $z_0$. Therefore, an important conclusion is that this NSOM configuration is not convenient for propagation loss measurements along the structure because both $P_{sca}$ and $P_1$ are expected to decrease in the same ratio.

To confirm our hypothesis that the probe scatters more efficiently the $y$-component of the electric field than that of the others, we calculated the spatial distribution of the electric field and we analyzed its components with the use of a finite element optical mode solver. We then compared them with the experimental result. To improve the spatial resolution of the optical image (Fig. 2(b)), we rescanned the waveguide with a window scan size of 5 $\mu m$ by 5 $\mu m$ and we set the lock-in amplifier to the second harmonic (Fig. 4). Finally, a transversal profile was taken from that image and is plotted as well. The results of the simulations are plotted in Fig. 4.

It is clearly observed in Fig. 4(a) that the calculated electric field power density does not match the measured profile. The calculated power density $|E|^2$ profile is highly confined inside the gap and does not change when the measurement is...
taken at different heights. The same observation is valid for the $x$-component (Fig. 4(b)). However, one can observe that the valley around $x = 0$ in the calculated $y$-component of the E-field at $y = 20 \text{nm}$ fairly matches the experimental profile even if there is no probe included in the calculations. Another interesting point in Fig. 4 is that the experimental profile is not symmetrical. This asymmetry is a consequence of the propagation of higher-order modes in the waveguide. Particularly, the linear superposition of the quasi-TE and -TM modes produces an asymmetry in the $y$-component of the field profile that depends on their excitation weight.

In summary, a vertically integrated plasmonic nanogap waveguide on silicon has been fabricated and characterized with a perturbation-NSOM. A quantitative analysis of the coupler was obtained via the application of the strongly coupled-mode theory. In conclusion, the signal measured in the perturbation-NSOM is proportional to the local optical power scattered by the main axis of the probe and it is normalized to the local optical power carried. The vertical oscillation of the probe results in a modulation of the detected signal; however, the main contribution to the NSOM signal comes from the scattering near the surface of the sample where the evanescent field is significant. The lock-in amplifier increases the signal-to-noise ratio and allows us to measure the harmonics of the optical signal. The high coupling efficiency of the coupler is the result of a large mode overlap. Such efficient integrated plasmonic nanogap waveguides open the door to further investigations.

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